

# SI7635DP-T1-GE3

### SI7635DP-T1-GE3 Information





Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## SI7635DP-T1-GE3 Specifications

Manufacturer Part Number	SI7635DP-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	PowerPAK? SO-8
Series	TrenchFET?
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	40A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	143nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4595pF @ 10V
Vgs (Max)	±16V
FET Feature	-
Power Dissipation (Max)	5W (Ta), 54W (Tc)
Rds On (Max) @ Id, Vgs	4.9 mOhm @ 26A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PowerPAK? SO-8
Package / Case	PowerPAK? SO-8
	Report errors?

#### SI7635DP-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

## SI7635DP-T1-GE3 Payment Methods



## SI7635DP-T1-GE3 Shipping Methods



If you have any question about SI7635DP-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com